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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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2SK2329(L), 2SK2329(S)

Silicon N Channel MOS FET

REJ03G1008-0200

(Previous: ADE-208-1356)

Rev.2.00 Sep 07, 2005

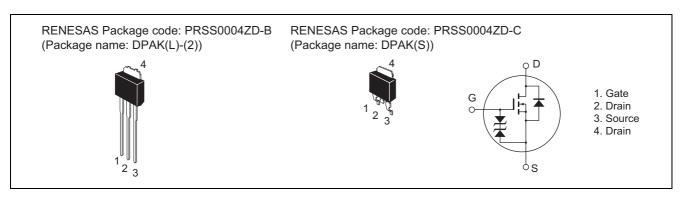
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- 2.5 V gate drive device can be driven from 3 V source
- Suitable for Switching regulator, DC-DC converter

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

| Item | Symbol | Ratings | Unit | |
|---|--------------------------|-------------|------|--|
| Drain to source voltage | V _{DSS} | 30 | V | |
| Gate to source voltage | V _{GSS} | ±10 | V | |
| Drain current | I _D | 10 | Α | |
| Drain peak current | I _{D(pulse)} *1 | 40 | Α | |
| Body to drain diode reverse drain current | I _{DR} | 10 | Α | |
| Channel dissipation | Pch*2 | 20 | W | |
| Channel temperature | Tch | 150 | °C | |
| Storage temperature | Tstg | −55 to +150 | °C | |

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1 %

2. Value at Tc = 25°C

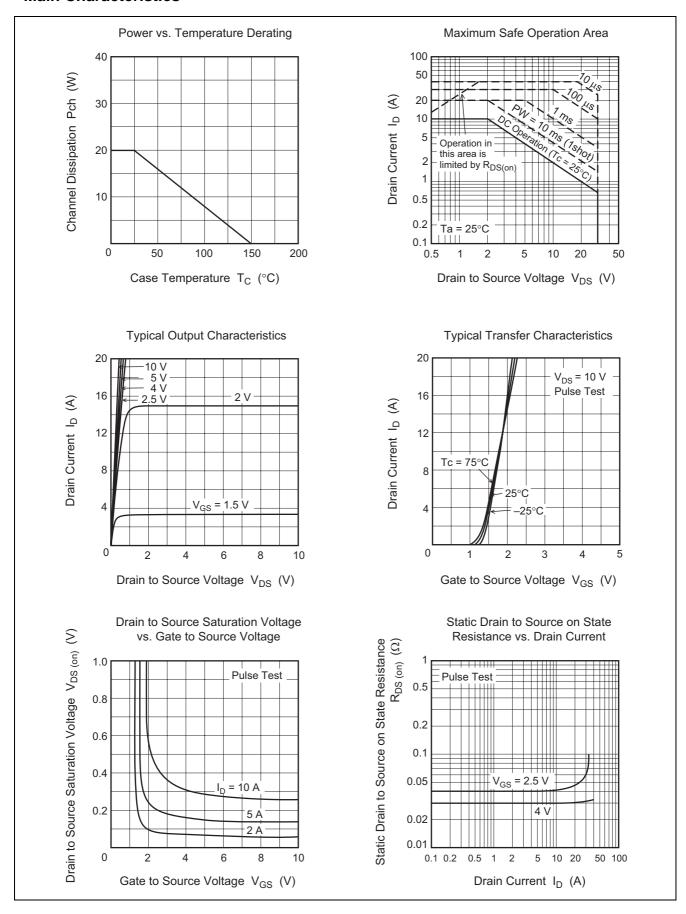
Electrical Characteristics

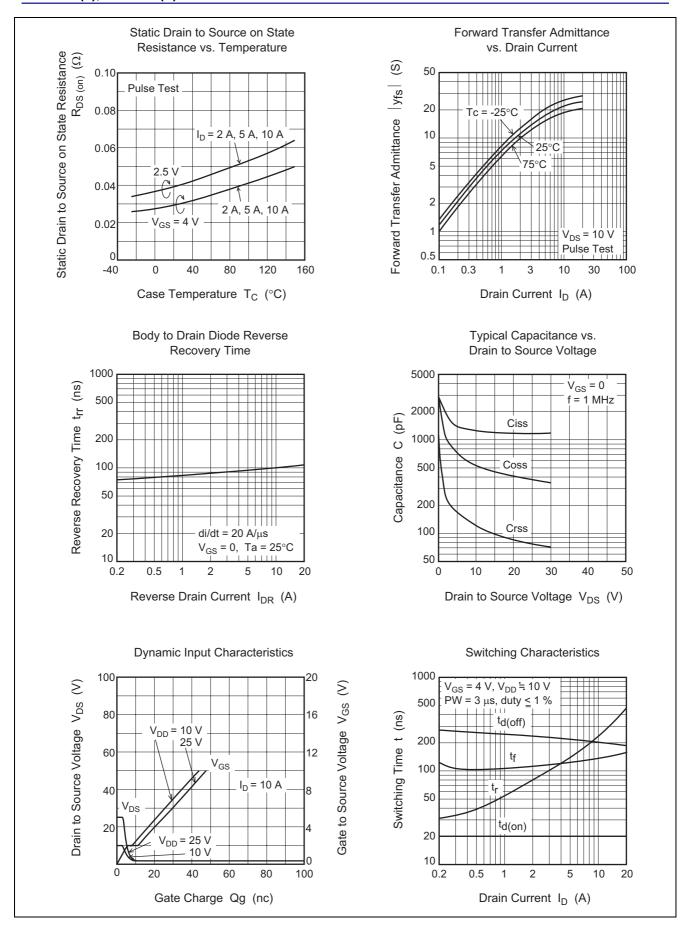
 $(Ta = 25^{\circ}C)$

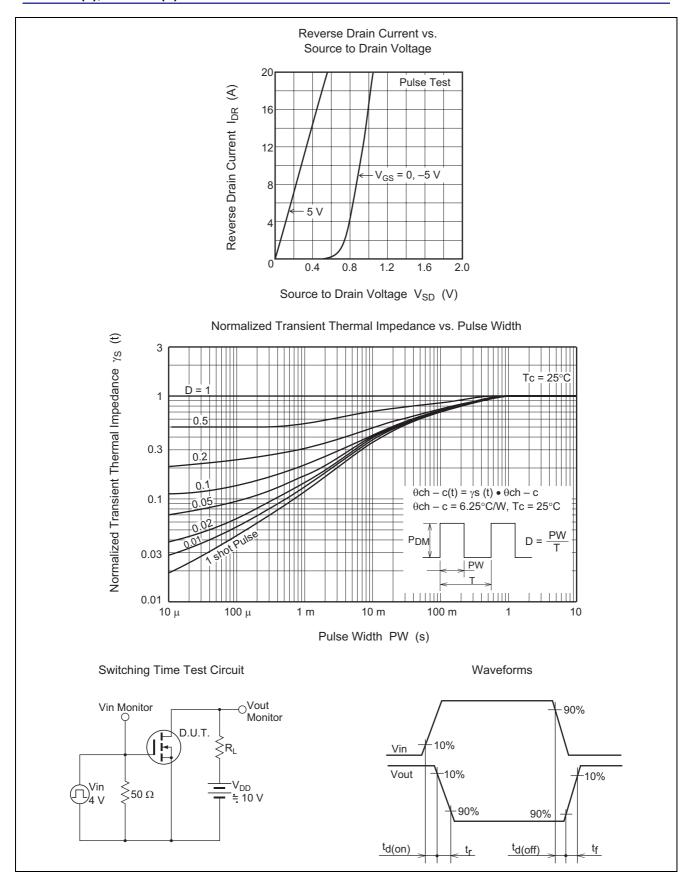
| Item | Symbol | Min | Тур | Max | Unit | Test Conditions |
|-------------------------------------|---------------------|-----|------|------|------|--|
| Drain to source breakdown voltage | $V_{(BR)DSS}$ | 30 | _ | _ | V | $I_D = 10 \text{ mA}, V_{GS} = 0$ |
| Gate to source breakdown voltage | $V_{(BR)GSS}$ | ±10 | _ | _ | V | $I_G = \pm 200 \ \mu A, \ V_{DS} = 0$ |
| Gate to source leak current | I _{GSS} | _ | _ | ±10 | μΑ | $V_{GS} = \pm 6.5 \text{ V}, V_{DS} = 0$ |
| Zero gate voltage drain current | I _{DSS} | _ | | 100 | μΑ | $V_{DS} = 25 \text{ V}, V_{GS} = 0$ |
| Gate to source cutoff voltage | $V_{GS(off)}$ | 0.4 | _ | 1.4 | V | $I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$ |
| Static drain to source on state | R _{DS(on)} | _ | 0.03 | 0.04 | Ω | $I_D = 5 \text{ A}, V_{GS} = 4 \text{ V}^{*3}$ |
| resistance | | _ | 0.04 | 0.06 | Ω | $I_D = 5 \text{ A}, V_{GS} = 2.5 \text{ V}^{*3}$ |
| Forward transfer admittance | y _{fs} | 10 | 18 | _ | S | $I_D = 5 \text{ A}, V_{DS} = 10 \text{ V}^{*3}$ |
| Input capacitance | Ciss | _ | 1250 | _ | pF | $V_{DS} = 10 \text{ V}, V_{GS} = 0,$ |
| Output capacitance | Coss | _ | 540 | _ | pF | f = 1 MHz |
| Reverse transfer capacitance | Crss | _ | 120 | _ | pF | |
| Turn-on delay time | t _{d(on)} | _ | 20 | _ | ns | $I_D = 5 A, V_{GS} = 4 V,$ |
| Rise time | t _r | _ | 145 | _ | ns | $R_L = 2 \Omega$ |
| Turn-off delay time | t _{d(off)} | _ | 225 | _ | ns | |
| Fall time | t _f | _ | 125 | _ | ns | |
| Body to drain diode forward voltage | V_{DF} | _ | 0.9 | _ | V | $I_F = 10 \text{ A}, V_{GS} = 0$ |
| Body to drain diode reverse | t _{rr} | _ | 100 | _ | ns | $I_F = 10 \text{ A}, V_{GS} = 0,$ |
| recovery time | | | | | | $di_F / dt = 20 A / \mu s$ |

Note: 3. Pulse Test

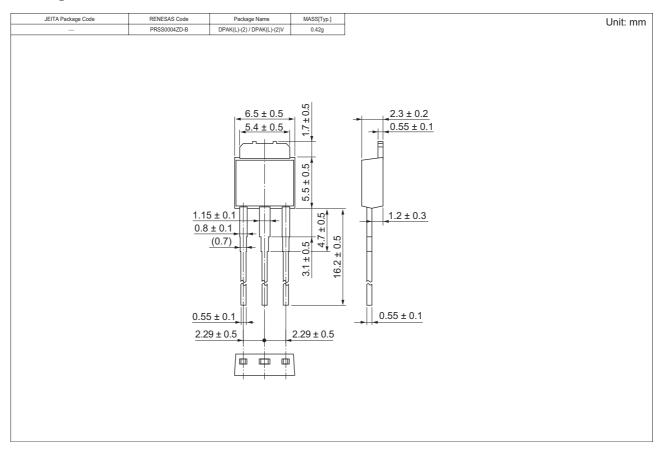
Main Characteristics

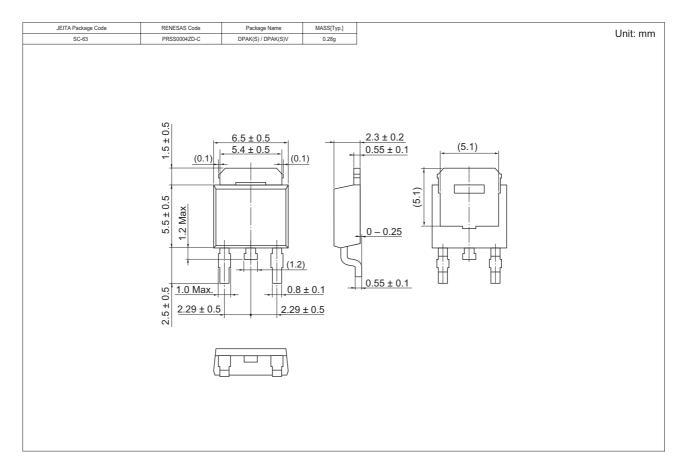






Package Dimensions





Ordering Information

| Part Name | Quantity | Shipping Container |
|--------------|----------|--------------------|
| 2SK3239L-E | 3000 pcs | Box (Sack) |
| 2SK3239STL-E | 3000 pcs | Taping |

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